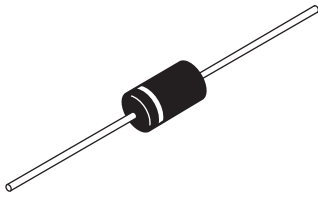




Schottky Rectifier, 1.1 A



DO-204AL



PRODUCT SUMMARY	
Package	DO-204AL (DO-41)
$I_{F(AV)}$	1.1 A
V_R	90 V, 100 V
V_F at I_F	See Electrical table
I_{RM}	1.0 mA at 125 °C
T_J max.	150 °C
Diode variation	Single die
E_{AS}	1.0 mJ

FEATURES

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)



DESCRIPTION

The VS-11DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	1.1	A
V_{RRM}		90/100	V
I_{FSM}	$t_p = 5 \mu s$ sine	85	A
V_F	1 Apk, $T_J = 25^\circ C$	0.85	V
T_J	Range	- 40 to 150	°C

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-11DQ09	VS-11DQ09-M3	VS-11DQ10	VS-11DQ10-M3	UNITS
Maximum DC reverse voltage	V_R	90	90	100	100	V
Maximum working peak reverse voltage	V_{RWM}					

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	$I_{F(AV)}$	50 % duty cycle at $T_C = 75^\circ C$, rectangular waveform		1.1	A
Maximum peak one cycle non-repetitive surge current See fig. 6	I_{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	85	
		10 ms sine or 6 ms rect. pulse		14	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25^\circ C$, $I_{AS} = 0.5 A$, $L = 8 mH$		1.0	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		0.5	A

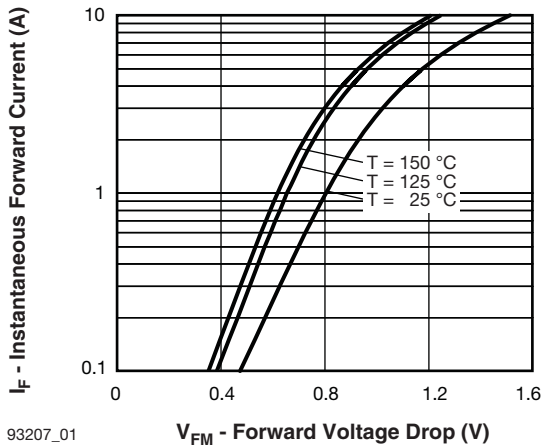


ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	1 A	$T_J = 25\text{ }^\circ\text{C}$	0.85	V
		2 A		0.96	
		1 A	$T_J = 125\text{ }^\circ\text{C}$	0.68	
		2 A		0.78	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	0.5	mA
		$T_J = 125\text{ }^\circ\text{C}$		1.0	
Typical junction capacitance	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		35	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s

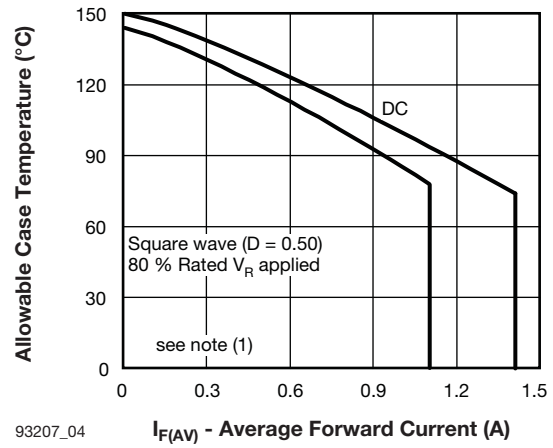
Note(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}, T_{Stg}$			- 40 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to ambient	R_{thJA}	DC operation Without cooling fin		100	$^\circ\text{C/W}$
Typical thermal resistance, junction to lead	R_{thJL}	DC operation See fig. 4		81	
Approximate weight				0.33	g
				0.012	oz.
Marking device		Case style DO-204AL (DO-41)		11DQ09	
				11DQ10	

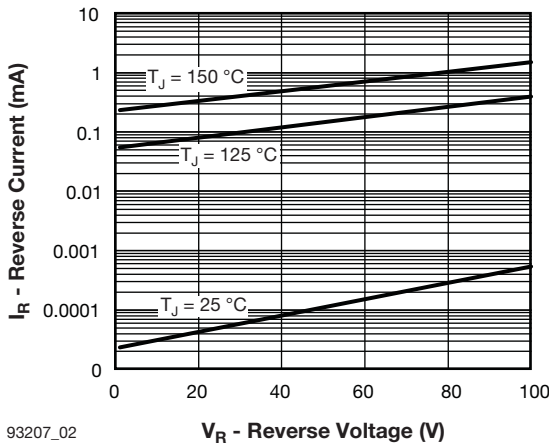
Note(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



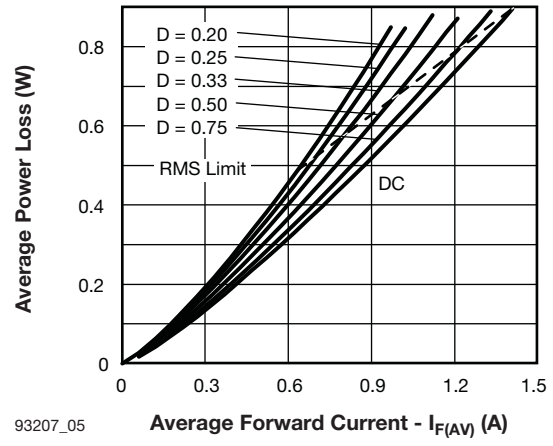
93207_01 **V_{FM} - Forward Voltage Drop (V)**
Fig. 1 - Maximum Forward Voltage Drop Characteristics



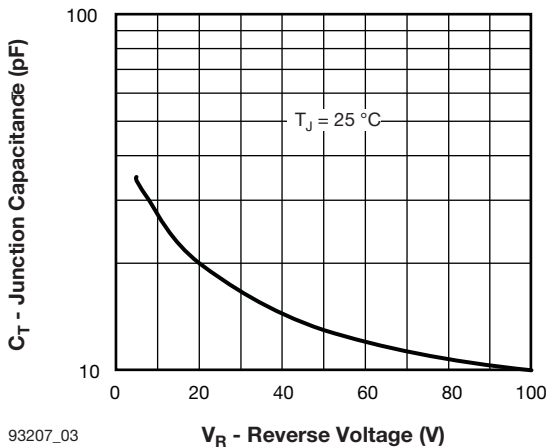
93207_04 **I_{F(AV)} - Average Forward Current (A)**
Fig. 4 - Maximum Ambient Temperature vs. Average Forward Current



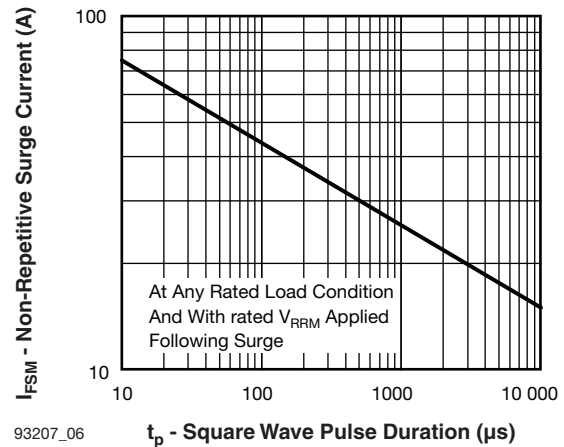
93207_02 **V_R - Reverse Voltage (V)**
Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



93207_05 **Average Forward Current - I_{F(AV)} (A)**
Fig. 5 - Forward Power Loss Characteristics



93207_03 **V_R - Reverse Voltage (V)**
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



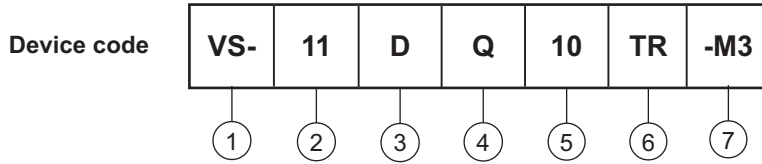
93207_06 **t_p - Square Wave Pulse Duration (μs)**
Fig. 6 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - 11 = 1.1 A (axial and small packages - current is x 10)
- 3** - D = DO-41 package
- 4** - Q = Schottky Q.. series
- 5** - 10 = Voltage ratings 09 = 90 V
10 = 100 V
- 6** - TR = Tape and reel package
None = Bulk package
- 7** - Environmental digit
 - None = Lead (Pb)-free and RoHS compliant
 - -M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-11DQ09	1000	1000	Bulk
VS-11DQ09TR	5000	5000	Tape and reel
VS-11DQ09-M3	1000	1000	Bulk
VS-11DQ09TR-M3	5000	5000	Tape and reel
VS-11DQ10	1000	1000	Bulk
VS-11DQ10TR	5000	5000	Tape and reel
VS-11DQ10-M3	1000	1000	Bulk
VS-11DQ10TR-M3	5000	5000	Tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95241
Part marking information	www.vishay.com/doc?95304
Packaging information	www.vishay.com/doc?95338



Axial DO-204AL (DO-41)

DIMENSIONS in millimeters (inches)

